

ELECTRON SPECTRO-MICROSCOPY (ESM) BEAMLINE



NATIONAL SYNCHROTRON LIGHT SOURCE II

SCIENTIFIC SCOPE

The technical scope of ESM is to prepare a high-flux, high resolving power beam covering the energy range 15–1,500 eV and serving two electron-microscopy end-stations: μ -ARPES and AC-XPEEM. Specific performance parameters for the two beams are:

ARPES

Photon Energy range: 15–1,500 eV
 Flux: $>10^{10}$ ph/s @ 100,000 resolving power
 Resolving Power: ~ 1 meV up to 70 eV photon energy; <30 meV up to 1,000 eV
 Spot Size: $\leq 1 \mu\text{m}$ > 60 eV (diffraction limited at lower energies)
 Light Polarization: hor.-lin, vert.-lin, left/right-circular above ~ 30 eV

XPEEM

Photon Energy range: 15–1,500 eV
 Flux: $>10^{12}$ ph/s @ 10,000 resolving power
 Resolving Power: same as ARPES branch
 Spot Size: $\sim 40 \mu\text{m}$
 Light polarization: hor.-lin, vert.-lin, left/right-circular above ~ 30 eV

BEAMLINE LAYOUT AND EXPERIMENTAL CAPABILITIES

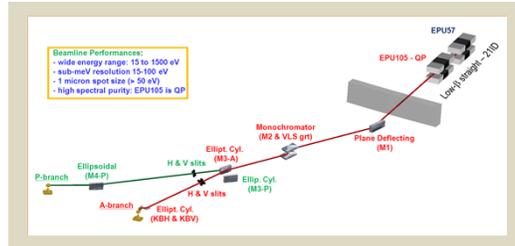
TECHNIQUES:

A-branch

- ARPES, SARPES, μ -ARPES
- XPS, XAS, XMCD

P-branch

- AC-PEEM, AC-LEEM



ENDSTATION DETAILS:

A-branch

- Smarct micro-scanning stage
- Scienta DA30
- Closed cycle LHe cryostats

P-branch

- Elmitec AC-LEEM III (Aberration-Corrected Low Energy Electron Microscope)

μ -SARPES

- high resolution (energy and momentum) electronic structure of solids;
- spin-polarized electronic bands of magnetic materials and non-magnetic materials with large spin-orbit interaction;
- scanning spectro-microscopy with 1 mm lateral resolution for chemical maps (core levels) or electronic structure maps (valence electrons)

AC-XPEEM

- energy filtered-XPEEM for chemical maps and (k_x, k_y) band mapping;
- aberration-correction for higher lateral resolution and higher transmission;
- non-destructive, fast-imaging technique allowing simultaneous surface sensitive microscopy and spectroscopy

Overview

PORT: 21-ID

SOURCE: 2 undulators (EPU105, EPU57)

ENERGY RANGE: 15 – 1000 eV

ENERGY RESOLUTION: $\Delta E/E = 10^{-5}$ - 10^{-4}

SPATIAL RESOLUTION: $1 \mu\text{m} / 40 \mu\text{m}$

CONSTRUCTION PROJECT: NEXT

BEAMLINE STATUS: Construction

AVAILABLE TO USERS: Spring 2017

Beamline Team

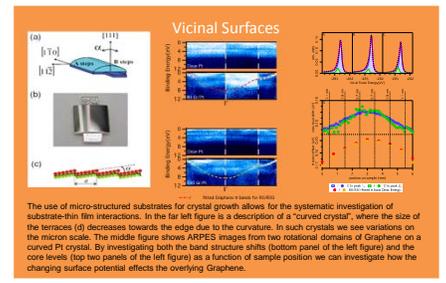
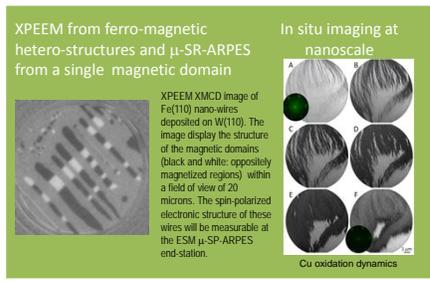
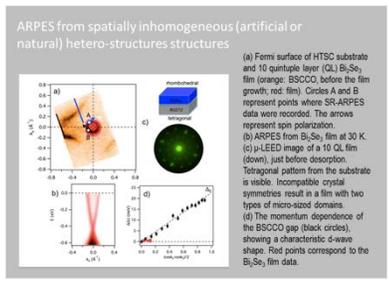
STAFF

- Elio Vescovo: lead beamline scientist
- Andrew Walter: beamline scientist
- Yi Zhu: mechanical engineer
- Sal Pjerov: designer
- Jun Ma: controls engineer
- Gary Nintzel: technician

ADVISORS

- Peter Johnson, Tony Valla (CMMSD)
- Jurek Sadowski, Peter Sutter (CFN)
- Francois Polac (Soleil), Rolf Follath (SLS)
- Tony Caruso (UMKC), Rudolf Tromp (IBM)
- Maya Kiskinova (ELETTRA)

SCIENTIFIC APPLICATIONS



- ARPES from spatially inhomogeneous samples, as well as artificially formed hetero-structures
- ARPES from polycrystalline or micro-crystal materials
- SP-ARPES from inside a magnetic domain
- XPEEM: fast, full-field probe for spatially resolved topographic, structural and spectroscopic measurements
- XPEEM/LEEM: in-situ growth and gas dosing capabilities for real-time investigation of surface processes.